

TURBOSWITCH™ "A". ULTRA-FAST HIGH VOLTAGE DIODE
MAIN PRODUCTS CHARACTERISTICS

$I_{F(AV)}$	15A
V_{RRM}	1200V
t_{rr} (typ)	55ns
V_F (max)	1.9V

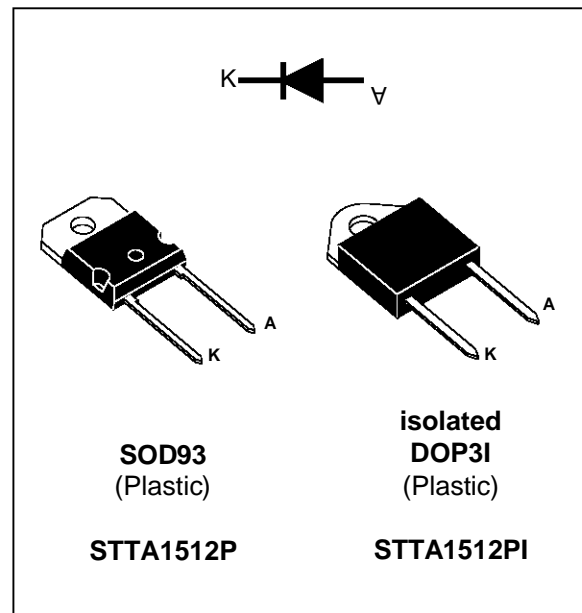
FEATURES AND BENEFITS

- ULTRA-FAST, SOFT AND NOISE-FREE RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY AND/OR HIGH PULSED CURRENT OPERATIONS.
- CECC APPROVED.

DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V.

TURBOSWITCH 1200V drastically cuts losses in all high voltage operations which require extremely fast, soft and noise-free power diodes. Due to their optimized switching performances they also highly decrease power losses in any associated switching IGBT or MOSFET in all "Freewheel

PRELIMINARY DATA


Mode" operations.

They are particularly suitable in Motor Control circuitries, or in the primary of SMPS as snubber, clamping or demagnetizing diodes, and also at the secondary of SMPS as high voltage rectifier diodes.

Packaged in SOD93 and in DOP3I, these 1200V devices are particularly intended for use on 3 phase 400V industrial mains.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	1200	V
V_{RSM}	Non repetitive peak reverse voltage	1200	V
$I_{F(RMS)}$	RMS forward current	50	A
I_{FRM}	Repetitive peak forward current (tp = 5 μs, f = 5kHz)	300	A
T_j	Max operating junction temperature	150	°C
T_{stg}	Storage temperature	-65 to 150	°C

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STTA1512P/PI

THERMAL AND POWER DATA

Symbol	Parameter	Conditions	Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	STTA1512P STTA1512PI	1.6 2.1	°C/W
P_1	Conduction power dissipation (see fig. 6)	$I_{F(AV)} = 15A$ $\delta = 0.5$ STTA1512P $T_C = 95^\circ C$ STTA1512PI $T_C = 78^\circ C$	34	W
P_{max}	Total power dissipation $P_{max} = P_1 + P_3$ ($P_3 = 10\% P_1$)	STTA1512P $T_C = 89^\circ C$ STTA1512PI $T_C = 70^\circ C$	38	W

STATIC ELECTRICAL CHARACTERISTICS (see Fig.6)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_F *	Forward voltage drop	$I_F = 15A$ $T_j = 25^\circ C$ $T_j = 125^\circ C$			2.1 1.9	V V
I_R **	Reverse leakage current	$V_R = 0.8$ $\times V_{RRM}$ $T_j = 25^\circ C$ $T_j = 125^\circ C$			100 6.0	μA mA

Test pulses widths : * $t_p = 380 \mu s$, duty cycle < 2%

** $t_p = 5 ms$, duty cycle < 2%

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING (see Fig.7)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	$T_j = 25^\circ C$ $I_F = 0.5 A$ $I_R = 1A$ $I_{rr} = 0.25A$ $I_F = 1 A$ $di_F/dt = -50A/\mu s$ $V_R = 30V$		55	105	ns
I_{RM}	Maximum reverse recovery current	$T_j = 125^\circ C$ $V_R = 600V$ $I_F = 15A$ $di_F/dt = -120 A/\mu s$ $di_F/dt = -500 A/\mu s$		TBD	TBD	A
S factor	Softness factor	$T_j = 125^\circ C$ $V_R = 600V$ $I_F = 15A$ $di_F/dt = -500 A/\mu s$		1.2		/

TURN-ON SWITCHING (see Fig.8)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	$T_j = 25^\circ C$ $I_F = 15 A$, $di_F/dt = 120 A/\mu s$ measured at, $1.1 \times V_{Fmax}$			TBD	ns
V_{Fp}	Peak forward voltage	$T_j = 25^\circ C$ $I_F = 15A$, $di_F/dt = 120 A/\mu s$ $I_F = 40A$, $di_F/dt = 500 A/\mu s$			TBD TBD	V

APPLICATION DATA

The 1200V TURBOSWITCH series has been designed to provide the lowest overall power losses in all high frequency or high pulsed current operations. In such applications (Fig 1 to 5), the way of calculating the power losses is given below :

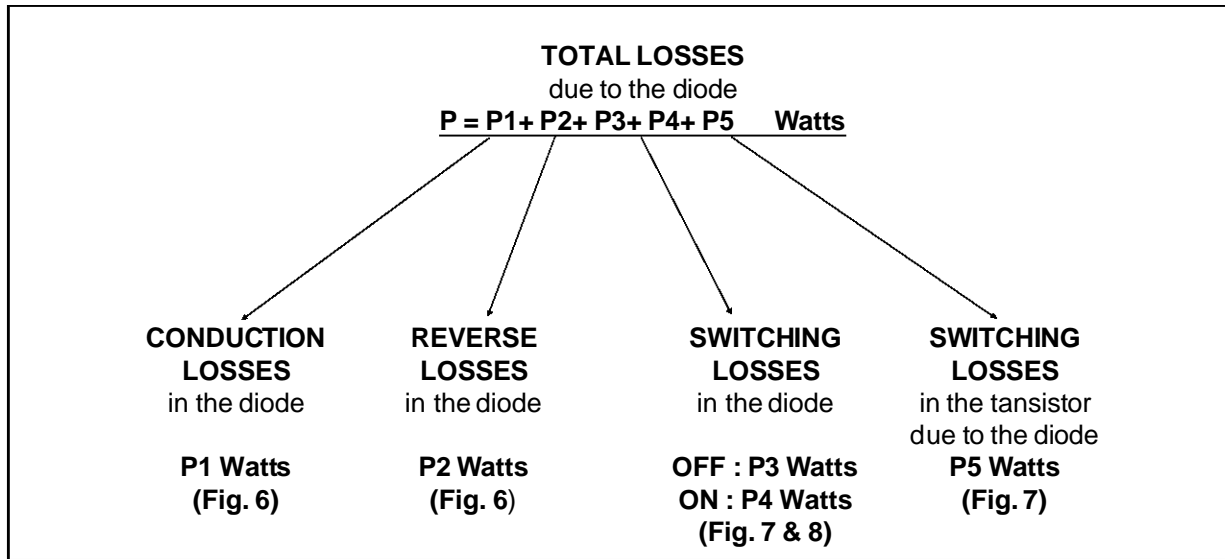


Fig. 1 : "FREEWHEEL" MODE.

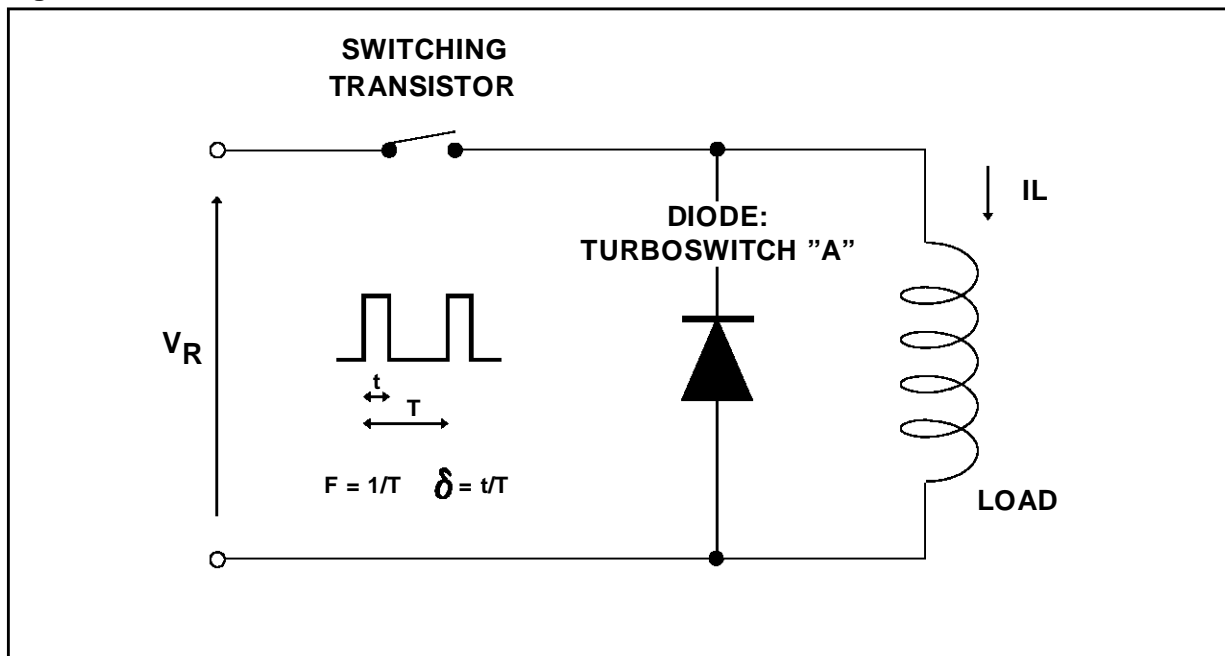


Fig. 2 : SNUBBER DIODE.

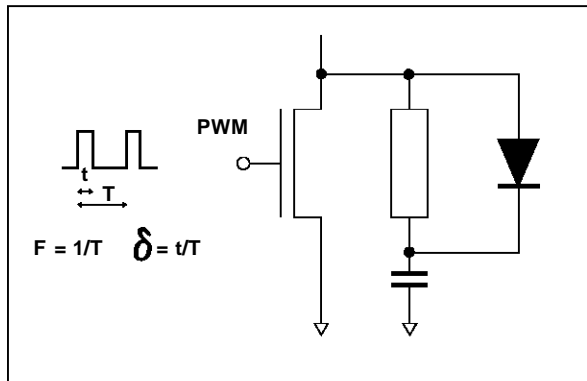


Fig. 3 : CLAMPING DIODE.

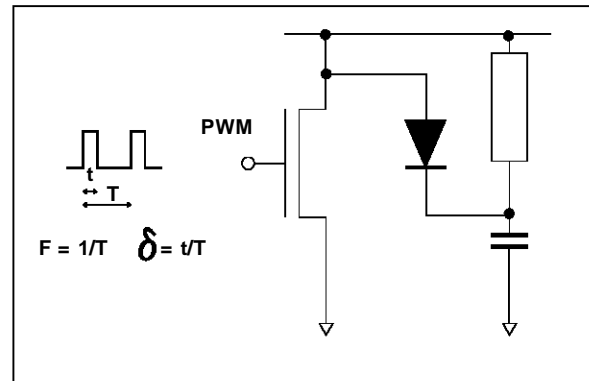


Fig. 4 : DEMAGNETIZING DIODE.

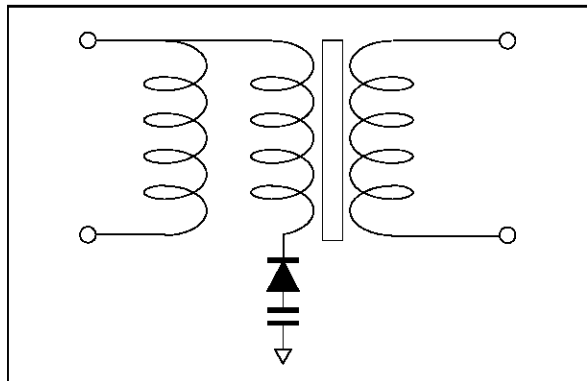
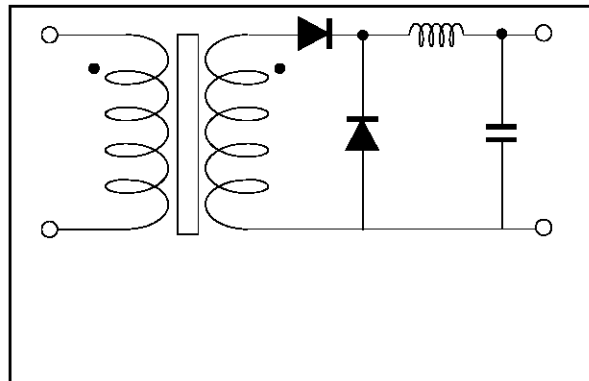
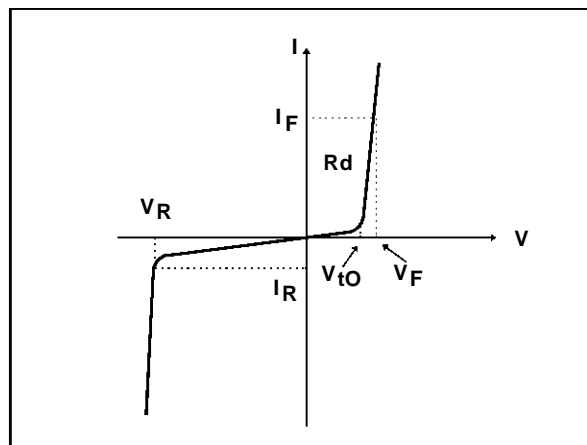


Fig. 5 : RECTIFIER DIODE.



STATIC & DYNAMIC CHARACTERISTICS . POWER LOSSES .

Fig. 6: STATIC CHARACTERISTICS



Conduction losses :

$$P1 = V_{t0} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$$

with

$$V_{t0} = 1.48 \text{ V}$$

$$R_d = 0.027 \text{ Ohm}$$

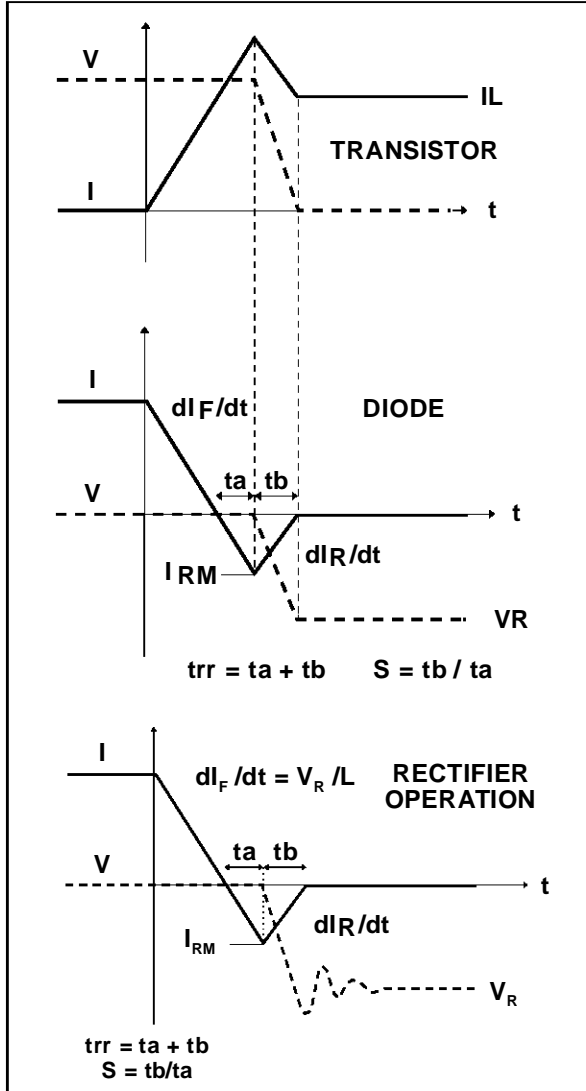
(Max values at 125°C, suitable for $I_{peak} < 3 \cdot I_{F(av)}$)

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

APPLICATION DATA (Cont'd)

Fig. 7: TURN-OFF CHARACTERISTICS



Turn-on losses :
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

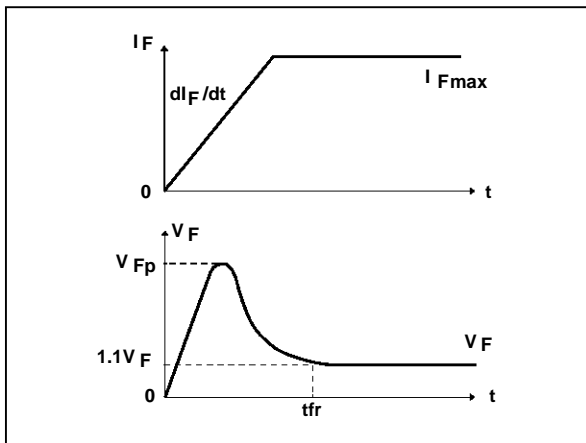
$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

Turn-off losses :
(with non negligible serial inductance)

$$P3' = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt} + \frac{L \times I_{RM}^2 \times F}{2}$$

P3,P3' and P5 are suitable for power MOSFET and IGBT

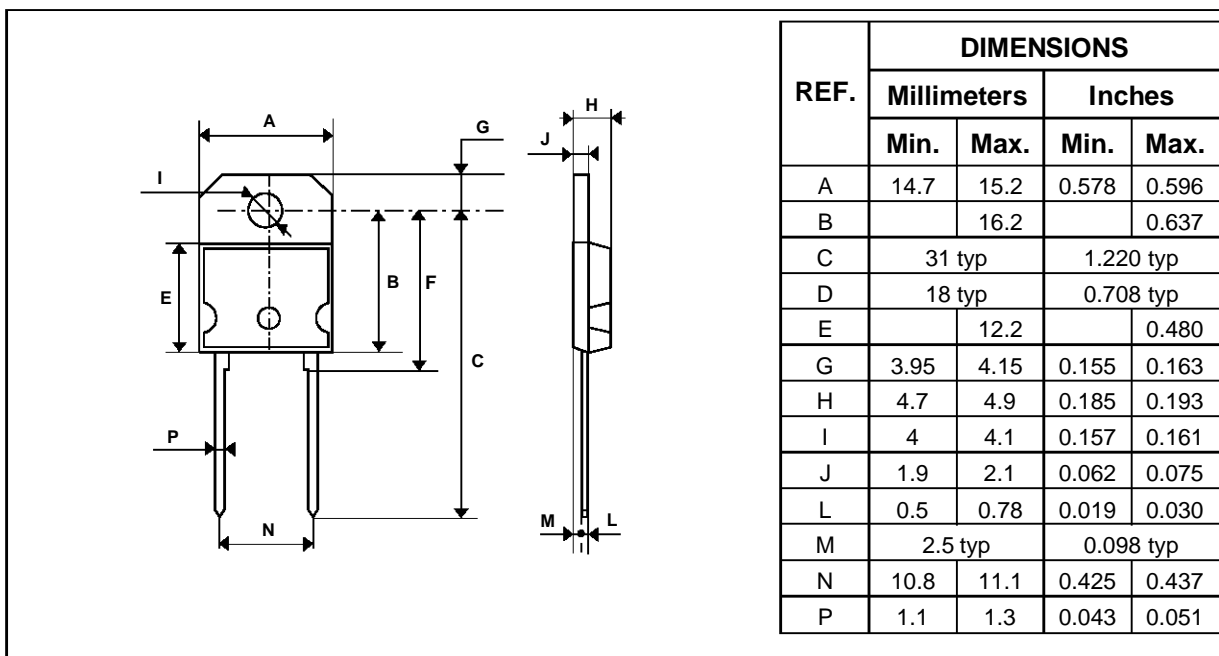
Fig. 8: TURN-ON CHARACTERISTICS



Turn-on losses :
 $P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{rr} \cdot F$

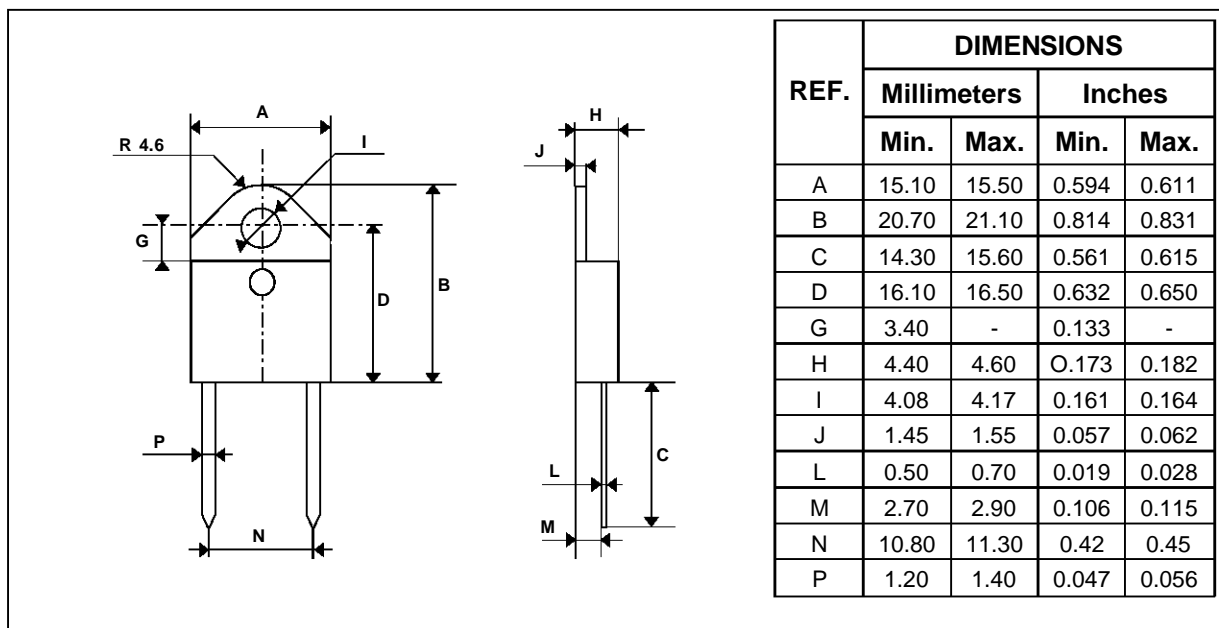
STTA1512P/PI

PACKAGE MECHANICAL DATA SOD93



Cooling method : C
 Marking : Type number
 Weight : 5.2 g
 Recommended torque value : 0.8m.N
 Maximum torque value : 1.0m.N

PACKAGE MECHANICAL DATA DOP3I (isoluted)



Cooling method : C
 Marking : Type number
 Weight : 4.6 g
 Recommended torque value : 0.8m.N
 Maximum torque value : 1.0m.N

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